TOSHIBA IGBT Module Silicon N Channel IGBT

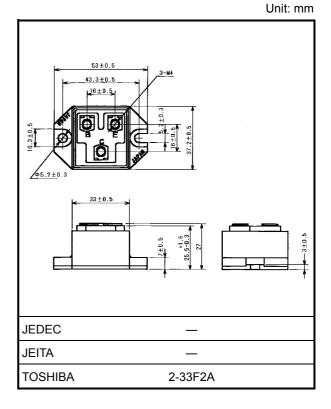
MG50J1BS11

High Power Switching Applications Motor Control Applications

- Enhancement-mode
- The electrodes are isolated from case.

Equivalent Circuit





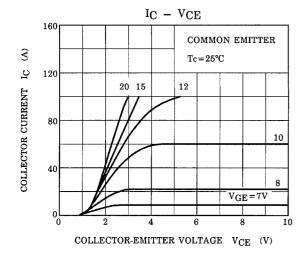
Maximum Ratings (Ta = 25°C)

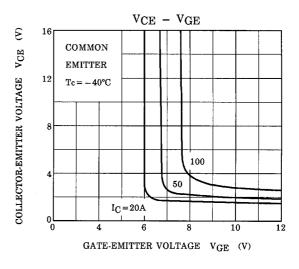
Characteristic		Symbol	Rating	Unit	
Collector-emitter voltage		V _{CES}	600	٧	
Gate-emitter voltage		V _{GES}	±20	V	
Collector current	DC	I _C	50	Α	
	1ms	I _{CP}	100		
Collector power dissipation		P _C	150	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-40 to 125	°C	
Isolation voltage		V _{Isol}	V _{Isol} 2500 (AC 1 minute)		
Screw torque (Terminal / mounting)		_	2/3	N·m	

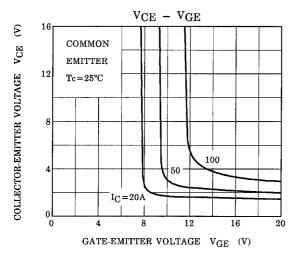
Electrical Characteristics (Ta = 25°C)

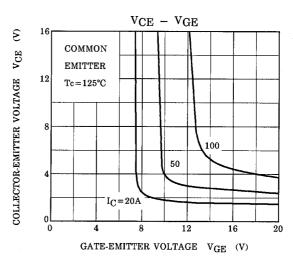
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GES}	V _{GE} = ±20V, V _{CE} = 0	_	_	±500	nA
Collector cut-off current		I _{CES}	V _{CE} = 600V, V _{GE} = 0	_	_	1.0	mA
Gate-emitter cut-off voltage		V _{GE} (OFF)	I _C = 50mA, V _{CE} = 5V	3.0	_	6.0	V
Collector-emitter saturation voltage		V _{CE (sat)}	I _C = 50A, V _{GE} = 15V	_	2.3	2.7	V
Input capacitance		C _{ies}	V _{CE} = 10V, V _{GE} = 0, f = 1MHz	1	3500	-	pF
Switching time	Rise time	t _r	+15V -15V 300V	1	0.3	0.8	μs
	Turn-on time	t _{on}		1	0.4	1.0	
	Fall time	t _f		1	0.6	1.0	
	Turn-off time	t _{off}			1.0	1.6	
Thermal resistance		R _{th (j-c)}	_	_	_	0.83	°C/W

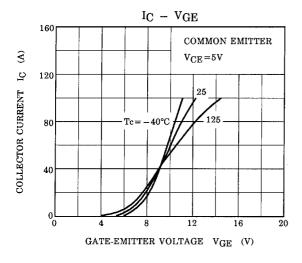
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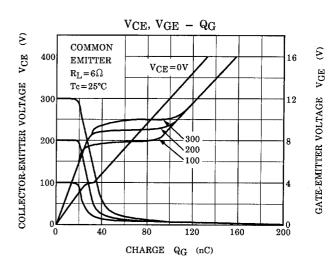


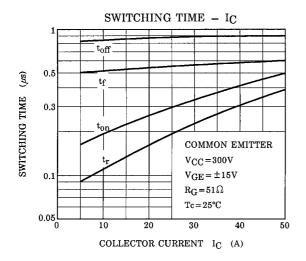


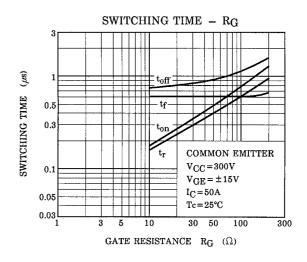


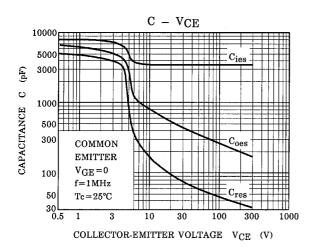


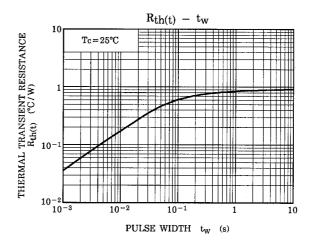


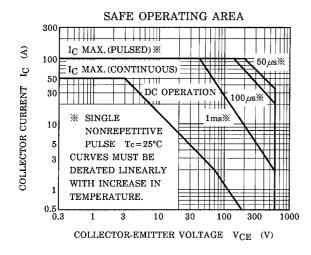


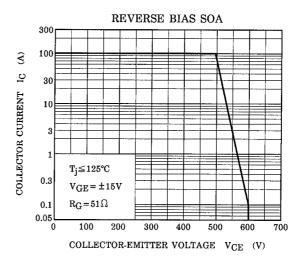












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